

# 1ED44176N01F

## Single-channel low-side gate driver IC with over-current protection

### **Features**

- Over-current detection with positive voltage input
- 0.5 V over-current threshold with accurate ±5% tolerance
- Single pin for fault output and enable
- Programmable fault clear time
- Under voltage lockout
- CMOS Schmitt-triggered inputs
- 3.3 V, 5 V and 15 V input logic compatible
- Output in phase with input
- Separate logic and power ground
- 2 kV ESD HBM
- RoHS compliant
- Evaluation board available: EVAL-1ED44176N01F

## **Potential applications**

- Digitally controlled PFC
- Air conditioner
- Home appliances
- Industrial applications
- General purpose low-side gate driver for single-ended topologies



### **Description**

The 1ED44176N01F is a low-voltage, power MOSFET and IGBT non-inverting gate driver. Proprietary latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output. The output driver features a current buffer stage. The 1ED44176N01F has OCP pin for over current protection sense and a FAULT status output (Once it is active, EN/FLT pin is internally pulled down.). There is a dedicated pin (FLTC) to program fault clear time. The EN/FLT needs to be outside pulled up to provide normal operation, pulling EN/FLT low disable the driver. Internal circuitry on VCC pin provides an under voltage lockout protection that holds output low until Vcc supply voltage is within operating range.

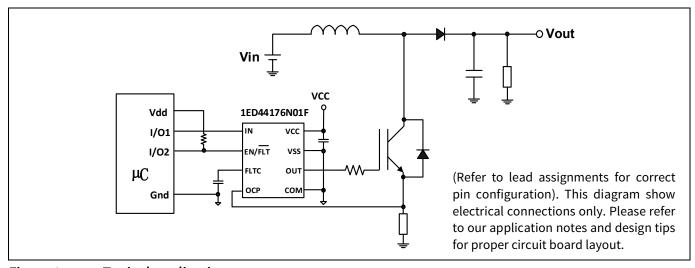


Figure 1 Typical application

## **Ordering information**

Product type	uct type Package Standard pack			Orderable part number
		Form	Quantity	
1ED44176N01F	PG-DSO-8	Tape and Reel	2500	1ED44176N01FXUMA1

#### **Product validation**

Qualified for industrial applications according to the relevant tests of JEDEC JESD47/22 and J-STD-020.

### 1ED44176N01F

# Single-channel low-side gate driver IC with over-current protection and fault/enable



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Block diagram

# 1 Block diagram

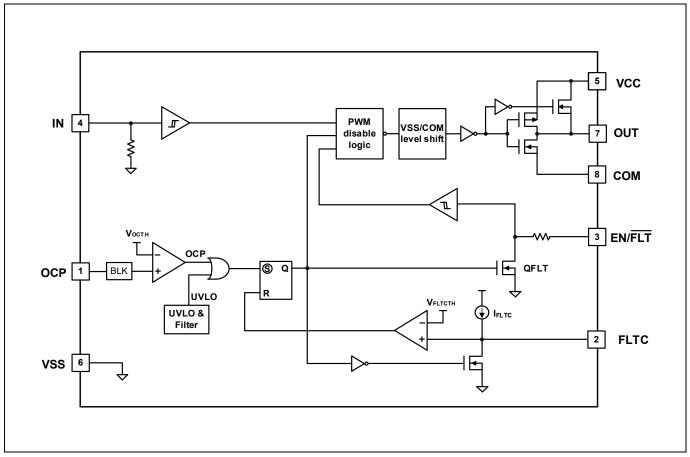


Figure 2 Block diagram

V 2.2



Pin configuration and functionality

# 2 Pin configuration and functionality

# 2.1 Pin configuration

Table 1 Pin configuration

Pin no.	Name	Function
1	ОСР	Current sense input
2	FLTC	Fault clear time program input
3	EN/FLT	<ol> <li>Enable and fault reporting pin, two functions:</li> <li>Logic input to enable I/O functionality. I/O logic functions when ENABLE is high and enable function is not latched.</li> <li>Fault reporting function like over-current or undervoltage lockout, this pin has negative logic and an open-drain output.</li> </ol>
4	IN	Logic input for gate driver output (OUT), in phase
5	VCC	Supply voltage
6	VSS	Logic ground
7	OUT	Gate drive output
8	СОМ	Gate drive return

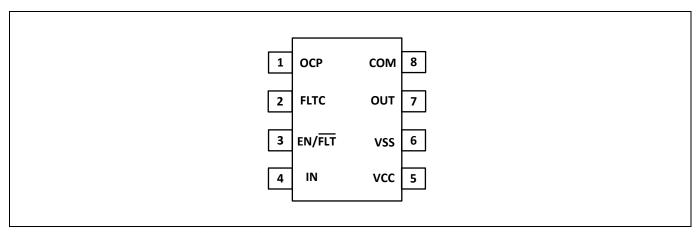


Figure 3 PG-DSO-8-70 (top view)

### Single-channel low-side gate driver IC with over-current protection and fault/enable



Pin configuration and functionality

# 2.2 nput/output logic truth table

Table 2 Input/output logic truth table

IN	UVLO 1)	OCP 2)	EN/FLT 3)	OUT	Note
L	Н	L	Н	L	OUT = L
Н	Н	L	Н	Н	OUT = H
X	L	х	L	L	OUT = L, EN/FLT = L, (UVLO protection will disable I/O logic until EN/FLT returns to high level.)
Х	Н	Н	L	L	OUT = L, EN/FLT = L, (Over current protection will disable I/O logic until EN/FLT returns to high level.)
X	Н	Х	L	L	OUT = L (Externally pull down EN/FLT pin will disable I/O logic until EN/FLT returns to high level.)

- 1) UVLO "L" state is under-voltage protection.
- 2) OCP "H" state is over-current protection.
- 3) EN/FLT "H" state is EN/FLT pin externally pulling up and internally pull down MOSFET ( $Q_{FLT}$ ) is off. (See block diagram.)



### **Qualification information**

# 3 Qualification information

		Industrial <sup>1)</sup>			
Qualification level		Comments: This family of ICs has passed JEDEC's Industrial			
Qualification level		qualification. Consumer qualification level is granted by			
		extension of the higher Industrial level.			
Moisture sensitivity level		MSL3 <sup>2)</sup> 260°C			
		(per JEDEC standard J-STD-020)			
	Charged device model	1000 V (Class C3)			
ESD	Charged device model	(per ANSI/ESDA/JEDEC standard JS-002)			
ESD	Liver on body model	Class 2			
	Human body model	(per ANSI/ESDA/JEDEC standard JS-001)			
IC latch up toot		Class II, Level A			
IC latch-up test		(per JESD78)			
RoHS compliant		Yes			

- 1) Higher qualification ratings may be available should the user have such requirements. Please contact your Infineon sales representative for further information.
- 2) Higher MSL ratings may be available for the specific package types listed here. Please contact your Infineon sales representative for further information.



### **Electrical parameters**

# 4 Electrical parameters

### 4.1 Absolute maximum ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. The device may not function or not be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. All voltage parameters are absolute voltages <u>referenced to VSS</u>. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Table 3 Absolute maximum ratings

Symbol	Definition		Min	Max	Units
V <sub>cc</sub>	Fixed supply voltage		- 0.5	25	
Vo	Output voltage (OUT)	COM - 0.5	$V_{cc} + 0.5$		
$V_{OCP}$	Voltage at current sense pin (OCP)	- 0.5	V <sub>cc</sub> +0.5		
Ven/ <del>flt</del>	Voltage at enable and fault reporting pin (EN/FLT)	- 0.5	$V_{cc} + 0.5$	V	
$V_{FLTC}$	Voltage at fault clear time program pin (FLTC)	- 0.5	$V_{cc} + 0.5$		
$V_{IN}$	Logic input voltage ( IN )	- 0.5	$V_{cc} + 0.5$		
COM	Driver return voltage		- 5	$V_{cc} + 0.5$	
$P_D$	Package power dissipation @ T <sub>A</sub> ≤ 25°C	PG-DSO-8	_	0.625	W
$Rth_{JA}$	Thermal resistance, junction to ambient	_	200	°C/W	
TJ	Junction temperature	- 40	150		
Ts	Storage temperature	- 55	150	°C	
T <sub>L</sub>	Lead temperature (soldering, 10 seconds)	·	_	260	

# 4.2 Recommended operating conditions

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to VSS unless otherwise stated in the table.

Table 4 Recommended operating conditions

Symbol	Definition	Min	Max	Units
V <sub>cc</sub>	Fixed supply voltage	12.7	20	
Vo	Output voltage	СОМ	V <sub>cc</sub>	
$V_{OCP}$	Voltage at current sense pin (OCP)	0	V <sub>cc</sub>	
VEN/FLT	Voltage at enable and fault reporting pin (EN/FLT)	0	V <sub>cc</sub>	V
V <sub>FLTC</sub>	Voltage at fault clear time program pin (FLTC)	0	V <sub>cc</sub>	
V <sub>IN</sub>	Logic input voltage ( IN )	0	V <sub>cc</sub>	
СОМ	Logic ground with respect to VSS	- 5	+5	
$T_A$	Ambient temperature	- 40	125	°C



### **Electrical parameters**

### 4.3 Static electrical characteristics

 $V_{CC}$  = 15 V, VSS=COM,  $T_A$  = 25°C unless otherwise specified. The  $V_{IN}$ ,  $V_{EN}$ ,  $V_{FLTCTH}$ ,  $V_{OCTH}$ ,  $I_{IN}$ ,  $I_{\overline{FLT}}$ , and  $I_{FLTC}$  parameters are referenced to VSS and are applicable to input leads: IN,EN/ $\overline{FLT}$ , FLTC and OCP. The  $V_0$  and  $I_0$  parameters are referenced to COM and are applicable to the output lead: OUT.

 Table 5
 Static electrical characteristics

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
V <sub>CCUV+</sub>	Vcc supply undervoltage positive going threshold	11.2	11.9	12.7		
V <sub>CCUV</sub> -	Vcc supply undervoltage negative going threshold	10.7	11.4	12.2		
$V_{CCUVH}$	Vcc supply undervoltage lockout hysteresis	_	0.5	_		
$V_{INL}$	Logic "0" input voltage (OUT = LO)	0.8	1	1.2		
V <sub>INH</sub>	Logic "1" input voltage (OUT = HI)		2.1	2.5	V	
V <sub>ENL</sub>	Logic "0" disable voltage	0.8	1	1.2	V	
$V_{ENH}$	Logic "1" enable voltage	1.7	2.1	2.5		
V <sub>FLTCTH</sub>	Fault clear threshold Voltage	2.4	2.7	3		
V <sub>OH</sub>	High level output voltage, V <sub>CC</sub> -V <sub>OUT</sub>	_	0.05	0.2		I <sub>0</sub> = 2 mA
V <sub>OL</sub>	Low level output voltage, V <sub>OUT</sub>	_	0.02	0.1		I <sub>0</sub> = 2 mA
V <sub>OCTH</sub>	Current limit threshold voltage	475	500	525	mV	
I <sub>IN+</sub>	Logic "1" input bias current IN pin	35	50	70	μA	V <sub>IN</sub> = 5 V
I <sub>IN-</sub>	Logic "0" input bias current IN pin	-5	_	_		V <sub>IN</sub> = 0 V
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> supply current	_	_	750		V <sub>IN</sub> = 0 V or 5 V
1	Output coursing short sirguit pulsed surrent	0.56	0.8			V <sub>0</sub> = 0 V
I <sub>O+</sub>	Output sourcing short circuit pulsed current	0.56	0.6	_	۸	PW ≤ 10 µs
1	Output sinking short circuit pulsed current	1.23	1.75		Α	V <sub>o</sub> = 15 V
I <sub>0-</sub>	Output sinking short circuit puised current	1.23	1.75	_		PW ≤ 10 µs
IFLT	EN/FLT pull down sinking current	20		_	mA	$V_{EN/\overline{FLT}} = 0.4 V$
$I_{FLTC}$	Fault clear sourcing current	-40	-25	-15	μΑ	$V_{FLTC} = 0 V$

### 4.4 Dynamic electrical characteristics

 $V_{CC}$  = 15 V,  $T_A$  = 25°C, and  $C_L$  = 1000 pF unless otherwise specified.

Table 6 Dynamic electrical characteristics

Symbol	Definition	Min	Тур	Max	Units	<b>Test Conditions</b>
ton	Turn-on propagation delay	_	50	95		
$t_{off}$	Turn-off propagation delay	_	50	95		Figure 6
$t_r$	Turn-on rise time	_	50	80		V <sub>IN</sub> pulse = 5 V
$t_{f}$	Turn-off fall time	_	25	35		
t <sub>EN</sub>	Enable propagation delay	_	50	95	ns	Figure 14
t <sub>DISA</sub>	Disable propagation delay	_	50	95		$V_{EN}$ pulse = 5 V
tocpdel	Over current protection propagation delay	_	380	470		Figure 10 Figure 11
tocpflt	OCP to low level EN/FLT signal delay	_	350	440		$R_{EN}=10k\Omega$ to Vcc $V_{OCP}$ pulse = 1 V
t <sub>FLTC</sub>	FAULT clear time	75	110	180	μs	Figure 10 Figure 11 C <sub>FLTC</sub> =1nF to VSS
t <sub>BLK</sub>	Over current protection blanking time		180	250	ns	Figure 11 $R_{FLT}=0\Omega$ , $G_{LT}=NC$ $V_{OCP}$ pulse = 1V
tv <sub>ccuv</sub>	VCC supply UVLO filter time	_	2	_	μs	Figure 8



## 5 Application information and additional details

Information regarding the following topics is included as subsections within this section of the datasheet.

- IGBT/MOSFET gate driver
- Switching and timing relationships
- Input logic compatibility
- Undervoltage lockout protection
- Over current protection (OCP)
- Fault reporting and programmable fault clear timer
- Enable input

See the 1ED44176N01F application note AN2018-03 Low - Side Driver with Over Current Protection and Fault/Enable for interface circuit examples and recommended layout guidelines.

### 5.1 GBT/MOSFET gate d river

The 1ED44176N01F is designed to drive MOSFET or IGBT power devices. Figure 4 and Figure 5 illustrate several parameters associated with the gate driver functionality of the driver. The output current of the driver, used to drive the gate of the power switch, is defined as  $I_0$ . The voltage that drives the gate of the external power switch is defined as  $V_{OUT}$ .

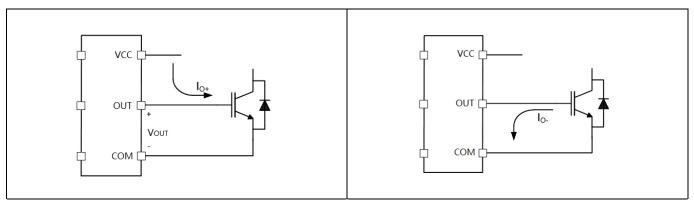


Figure 4 Gate output sourcing current

Figure 5

Gate output sinking current

## 5.2 Switching and timing relationships

The relationships between the input and output signals of the 1ED44176N01F are illustrated below in Figure 6. From the figure, we can see the definitions of several timing parameters (i.e.  $t_{on}$ ,  $t_{off}$ ,  $t_r$ , and  $t_f$ ) associated with this device.

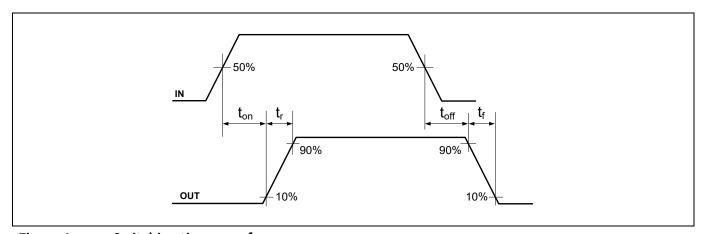


Figure 6 Switching time waveforms



### 5.3 nput logic c ompatibility

The input of this IC is compatible with standard CMOS and TTL outputs. The 1ED44176N01F has been designed to be compatible with 3.3 V, 5 V and 15 V logic-level signals. The input high threshold  $(V_{INH})$  is typ. 2.1 V and low threshold  $(V_{INL})$  is typ. 1 V. Input hysteresis offers enhanced noise immunity. The 1ED44176N01F includes an important feature: wherein, whenever the input pin is in a floating condition, the output is held in the low state. This is achieved using GND pull-down resistors on the input pin. Figure 7 illustrates an input signal to the 1ED44176N01F, its input threshold values, and the logic state of the IC as a result of the input signal.

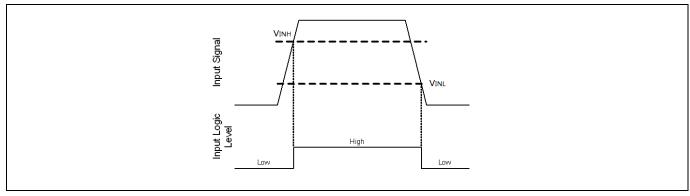


Figure 7 IN input thresholds

### 5.4 Undervoltage lockout (Vcc)

The 1ED44176N01F has an internal UVLO protection feature on the VCC pin supply circuit blocks. Upon power-up, if the VCC voltage fails to reach the  $V_{CCUV^+}$  threshold, the driver cannot turn on. Additionally, if the VCC voltage decreases below the  $V_{CCUV^-}$  threshold and the VCC bias voltage remains lower than the  $V_{CCUV^-}$  threshold exceeding UVLO filter time ( $t_{VCCUV}$ ) during operation, the undervoltage lockout circuitry will recognize a fault condition and shut-down the drive output. The  $EN/\overline{FLT}$  will then transit to the low state to inform the controller of the fault condition, regardless of the status of the IN input pin. The  $t_{VCCUV}$  about  $2\mu$ s helps to suppress noise from the UVLO circuit, so that negative-going voltage spikes at the supply pin will avoid parasitic UVLO events.

When VCC is higher than  $V_{CCUV+}$  and longer than  $t_{FLTC}$ , EN/ $\overline{FLT}$  becomes high and the OUT will follow the input signal IN. (Figure 8 shows the UVLO time is shorter than  $t_{FLTC}$ .)

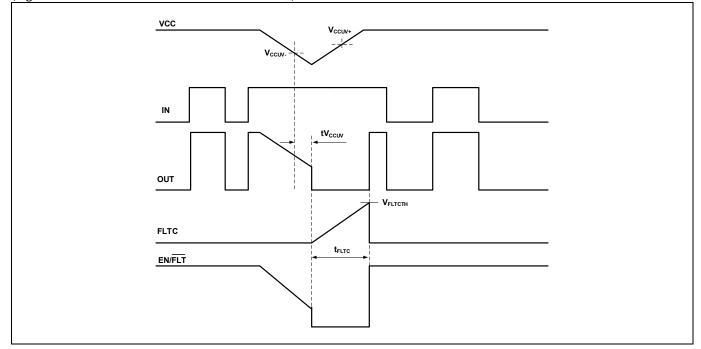


Figure 8 Vcc under voltage protection waveform definitions one

#### Single-channel low-side gate driver IC with over-current protection and fault/enable



### Application information and additional details

Once EN/FLT enters UVLO mode, EN/FLT keeps low until  $t_{FLTC}$  is over and VCC supply voltage higher than  $V_{CCUV+}$ . (Figure 9 shows the UVLO time is longer than  $t_{FLTC}$ .)

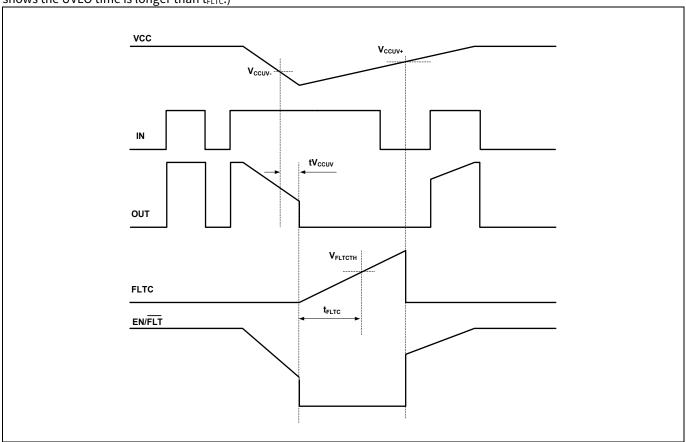


Figure 9 Vcc under voltage protection waveform definitions two

## 5.5 Over current protection (OCP)

The 1ED44176N01F has a function of over current protection with a threshold  $V_{OCTH}$  at the OCP pin. The voltage at this pin is the voltage across the current sense resistor. To avoid false tripping due to the fast high current switch on transient that occurs at the switch on of MOSFET or IGBT resulting from the circuit parasitic capacitors, there is blanking interval which disables over current detection for the period of  $t_{BLK}$ . (An additional RC filter is recommended, if the internal  $t_{BLK}$  is not sufficient to suppress the noise.) After  $t_{BLK}$  and the voltage of OCP pin is over  $V_{OCTH}$ , the 1ED44176N01F causes fault logic to initiate a fault shutdown sequence. This sequence starts with the generation of a fault signal. The internal MOSFET  $Q_{FLT}$  is turned on and  $EN/\overline{FLT}$  pin is pulled down.

At the same time the 1ED44176N01F terminates the present cycle, and the gate output is immediately pulled down with internal propagation delay ( $t_{OCPDEL}$ ), see the Figure 10 and Figure 11.

Figure 10 is the diagram of 1ED44176N01F in Boost application. And Figure 11 is the typical waveforms of the application.

If EN/FLT pin enters over current protection mode, EN/FLT pin keeps low until fault clear time is over and OCP terminal voltage lower than over current threshold voltage.

Figure 11 shows the OCP time is shorter than t<sub>FLTC</sub>. Figure 12 shows the OCP time is longer than t<sub>FLTC</sub>.



Note: If OCP fault condition is removed and the time is longer than fault clear time ( $t_{FLTC}$ ), the internal pull down MOSFET  $Q_{FLT}$  of EN/FLT is released and EN/FLT will be pull up again with Vdd, then the OUT will follow the input signal IN.

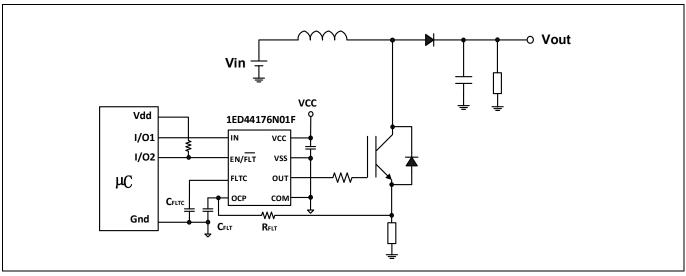


Figure 10 1ED44176N01F in Boost application

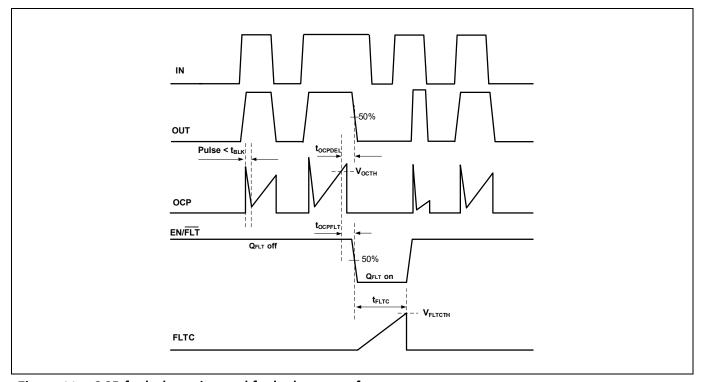


Figure 11 OCP fault detection and fault clear waveforms one



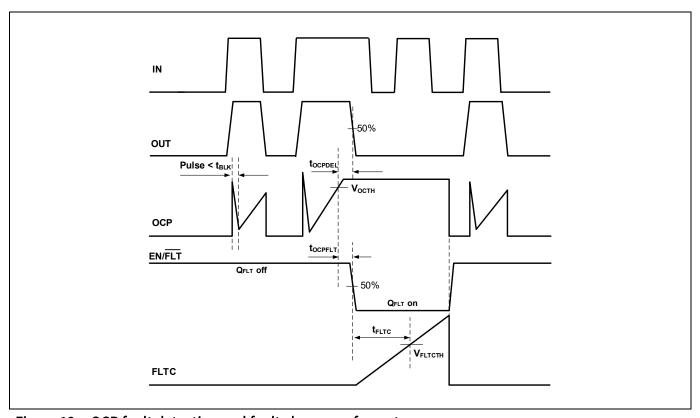


Figure 12 OCP fault detection and fault clear waveforms two

# 5.6 Fault reporting and programmable fault clear timer

The 1ED44176N01F provides a dedicated fault reporting output pin (EN/ $\overline{FLT}$ ) and a programmable fault clear time pin (FLTC). There are two situations which would cause the driver to report a fault via the EN/ $\overline{FLT}$  pin. The first is an under voltage condition of VCC and the second is if the OCP pin recognizes a fault. Once the fault condition occurs, the EN/ $\overline{FLT}$  pin is internally pulled down to VSS. The EN/ $\overline{FLT}$  output stays in the low state until the fault condition has been removed and the fault clear timer expires; once the fault clear timer expires, the voltage on the EN/ $\overline{FLT}$  pin will return to its external pull-up voltage.

The length of the fault clear time period ( $t_{FLTC}$ ) is programmed by external capacitor which connected between FLTC and VSS ( $C_{FLTC}$ ). See Figure 10.

The length of the fault clear time period can be determined by using the equation below.

$$t_{FLTC} = C_{FLTC} * V_{FLTCTH} / I_{FLTC}$$

Note: If the OCP last time is longer than  $t_{FLTC}$ , the EN/ $\overline{FLT}$  output keeps low until the OCP input voltage lower than OCP threshold voltage. See Figure 12.



### 5.7 Enable input

1ED44176N01F provides an enable functionality that allows to shutdown or to enable the output. When EN/FLT is pulled up (the enable voltage is higher than  $V_{ENH}$ ) the output is able to operate normally, pulling EN/FLT low (the enable voltage is lower than  $V_{ENL}$ ) the output is disable. The enable function is not latched. The relationships between the input, output and enable signals of the 1ED44176N01F are illustrated below in Figure 13 - Figure 15. From these figures, we can see the definitions of several timing parameters and threshold voltages (i.e.  $t_{DISA}$ ,  $t_{EN}$ ,  $V_{ENH}$  and  $V_{ENL}$ ) associated with this device.

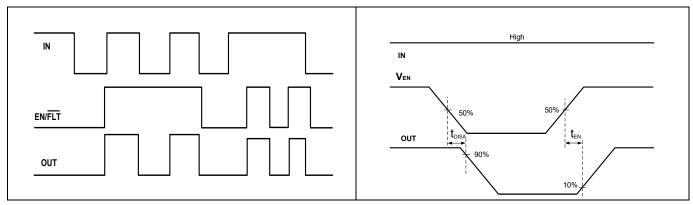


Figure 13 Input/output/enable pins timing diagram Figure 14 EN pin switching time waveform

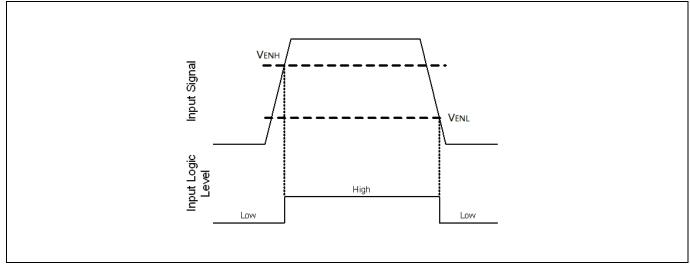


Figure 15 EN input thresholds



V 2.2

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#### Package outline

# 6 Package outline

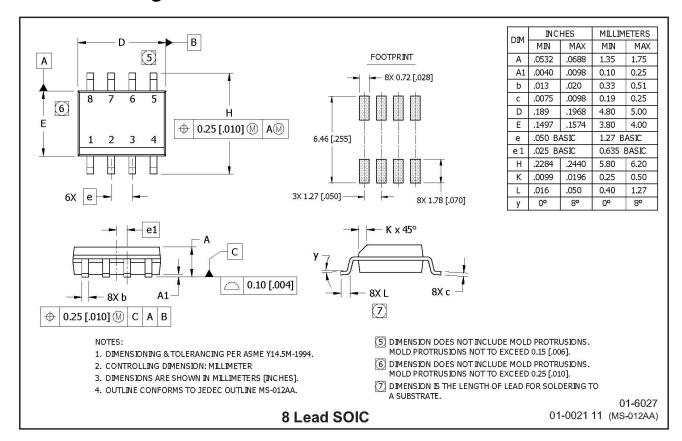


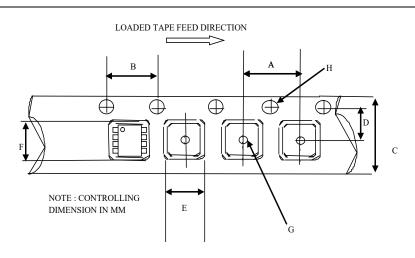
Figure 16 Package outline



V 2.2

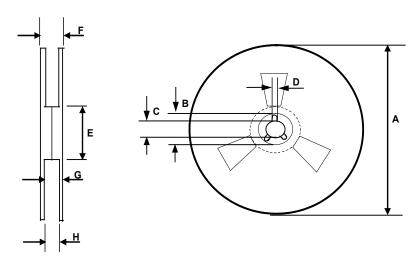
Tape and reel details: PG-DSO8

#### Tape and reel details: PG-DSO8 7



#### CARRIER TAPE DIMENSION FOR 8SOICN

	Metric		Imperial		
Code	Min	Max	Min	Max	
Α	7.90	8.10	0.311	0.318	
В	3.90	4.10	0.153	0.161	
B C D	11.70	12.30	0.46	0.484	
	5.45	5.55	0.214	0.218	
E	6.30	6.50	0.248	0.255	
F	5.10	5.30	0.200	0.208	
G	1.50	n/a	0.059	n/a	
Н	1.50	1.60	0.059	0.062	



REEL DIMENSIONS FOR 8SOICN

Metric		Imperiai		
Min	Max	Min	Max	
329.60	330.25	12.976	13.001	
20.95	21.45	0.824	0.844	
12.80	13.20	0.503	0.519	
1.95	2.45	0.767	0.096	
98.00	102.00	3.858	4.015	
n/a	18.40	n/a	0.724	
14.50	17.10	0.570	0.673	
12.40	14.40	0.488	0.566	
	Min 329.60 20.95 12.80 1.95 98.00 n/a 14.50	Min         Max           329.60         330.25           20.95         21.45           12.80         13.20           1.95         2.45           98.00         102.00           n/a         18.40           14.50         17.10	Min         Max         Min           329.60         330.25         12.976           20.95         21.45         0.824           12.80         13.20         0.503           1.95         2.45         0.767           98.00         102.00         3.858           n/a         18.40         n/a           14.50         17.10         0.570	

Figure 17 Tape and reel details



Part marking information

# 8 Part marking information

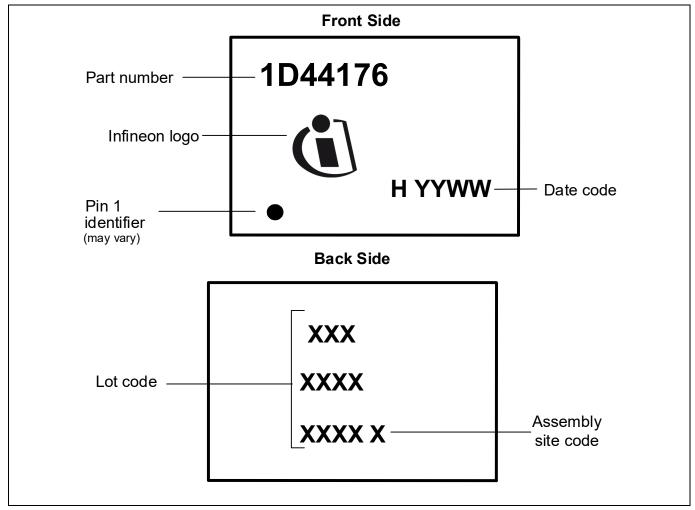


Figure 18 Part marking information



Similar products

# 9 Similar products

Channel s	Typ. gate drive (Io+/Io-)	Part number	Max supply voltage	UVLO (on/off)	Typ. prop. delay (on/off)	Logic	Package options
	Α		V	V	ns		
	0.3 / 0.5	IR44252L	20	5 / 4.15	50 / 50	Single non-inverting channel Dual OUT pins	SOT23-5L
1	1.5 / 1.5	IRS44273L	25	10.2 / 9.2	50 / 50	Single non-inverting channel Dual OUT pins	SOT23-5L
		IR44273L	20	5 / 4.15	50 / 50	Single non-inverting channel Dual OUT pins	SOT23-5L
		IR44272L	20	5 / 4.15	50 / 50	Single non-inverting channel ENABLE	SOT23-5L
		IRS4426S	25		50 / 50	Dual inverting channels	SOIC-8L
2	2.3 / 3.3	IRS44262S	20	10.2 / 9.2	50 / 50	Dual inverting channels	SOIC-8L
	2.3 / 3.3	IRS4427S	25		50 / 50	Dual non-inverting channels	SOIC-8L
		IRS4428S	25		50 / 50	Single inverting channel Single non-inverting channel	SOIC-8L

# 10 Related documents

- 1. AN2018-03 Low Side Driver with Over Current Protection and Fault/Enable
- 2. AN2018-11 1ED44176N01F evaluation board

### 1ED44176N01F

Single-channel low-side gate driver IC with over-current protection and fault/enable



**Revision history** 

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Document version	Date of release	Description of changes
2.0	2018-06-27	Create the document V 2.0
2.1	2019-06-13	Optimize parameter in table 6
2.2	2019-10-15	Optimize parameter in table 3

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Edition 2019-10-15
Published by
Infineon Technologies AG
81726 Munich, Germany

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Document reference Z8F62869814

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